

40V HIGH CURRENT LOW LEAKAGE SCHOTTKY DIODE
Product Summary

V_{RRM} (V)	I_o (A)	V_F Max (V) @ +25°C	I_R Max (μA) @ 30V +25°C
40	2	0.54	40

Features and Benefits

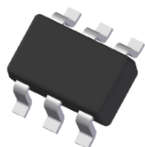
- Low Equivalent on Resistance
- Extremely Low Leakage
- Low V_F , Fast Switching Schottky
- Package Thermally Rated to +150°C
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Description and Applications

A surface mount Schottky Barrier Diode featuring low forward voltage drop suitable for high frequency rectification and reverse voltage protection.

- DC – DC Converters
- Strobes
- Mobile Phones
- Charging Circuits
- Motor Control

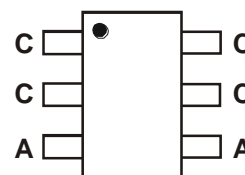
SOT-26



Top View



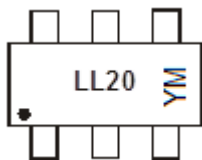
Device Symbol


 Top View
Pin Out

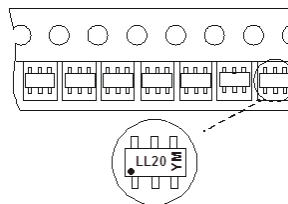
Ordering Information

Device	Packaging	Shipping
ZLLS2000TA	SOT26	3,000/Tape & Reel
ZLLS2000TC	SOT26	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For Packaging Details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


LL20 = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: D = 2016)
 M or \bar{M} = Month (ex: 9 = September)



Date Code Key

Year	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	D	E	F	G	H	I	J	K	L	M	N

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

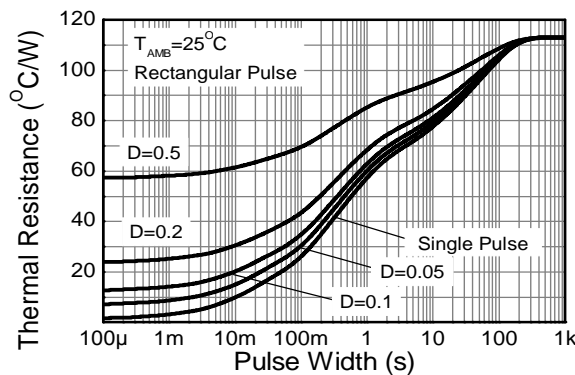
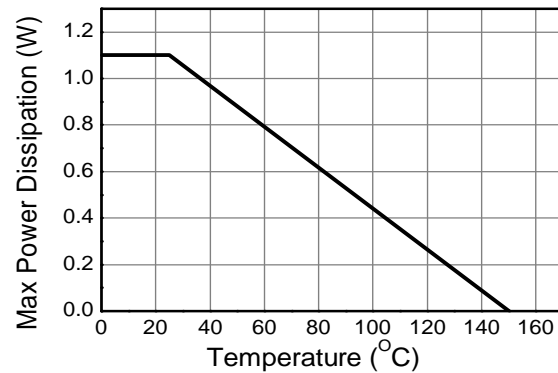
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Continuous Reverse Voltage	V _{RRM}	40	V
Forward Current	I _F	2.2	A
Peak Repetitive Forward Current	I _{FPK}	3.55	A
Rectangular Pulse Duty Cycle			
Non Repetitive Forward Current	I _{FSM}	36	A
		12	A

Thermal Characteristics

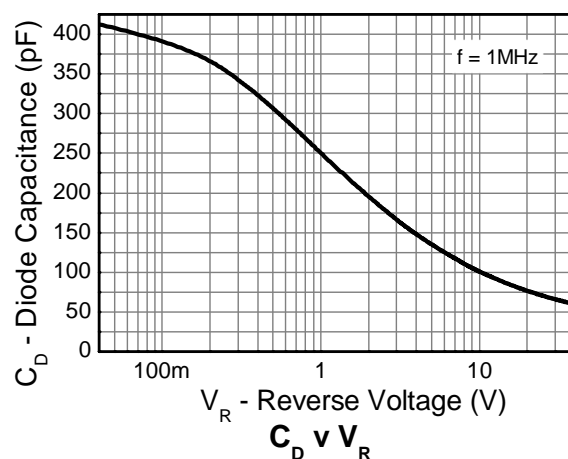
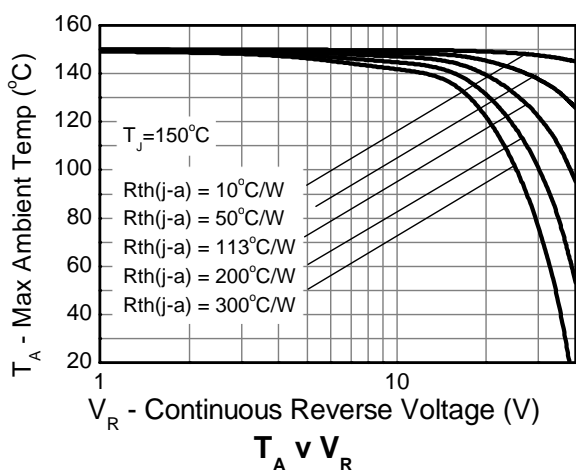
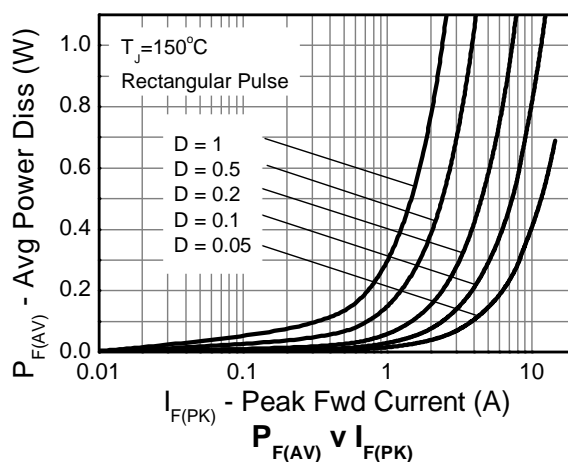
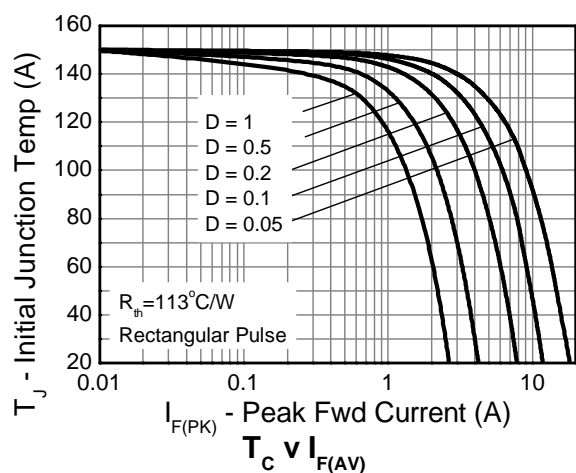
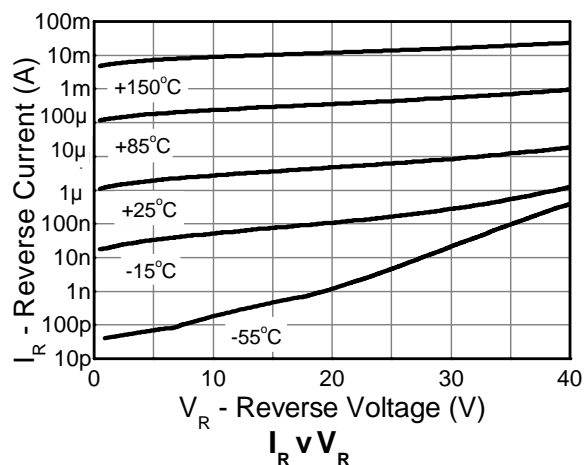
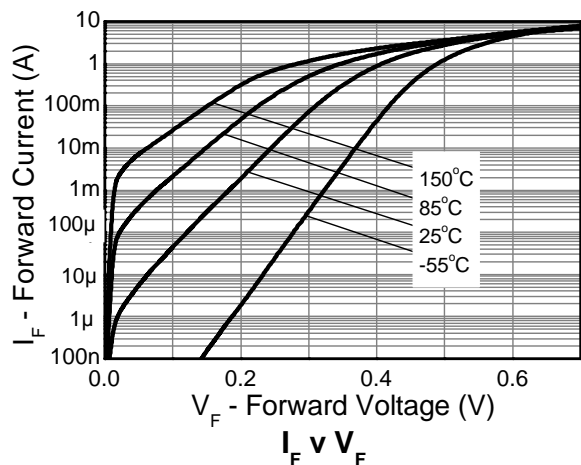
Characteristic	Symbol	Value	Unit
Power Dissipation @T _A = +25°C		-	-
Single Die Continuous	P _D	1.1	W
Single Die Measured at t < 5 secs		1.71	W
Junction to Ambient (Note 5)	R _{θJA}	113	°C/W
Junction to Ambient (Note 6)	R _{θJA}	73	°C/W
Storage Temperature Range	T _{STG}	-55 to +150	°C
Junction Temperature	T _J	+150	°C

Notes: 5. For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 6. For a device mounted on FR-B PCB measured at t < 5secs.


Transient Thermal Impedance

Derating Curve
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage	V _{(BR)R}	40	-	-	V	I _R = 1mA
Forward Voltage (Note 7)	V _F	-	285	-	mV	I _F = 50mA
		-	305	-		I _F = 100mA
		-	335	-		I _F = 250mA
		-	365	390		I _F = 500mA
		-	403	430		I _F = 1A
		-	433	490		I _F = 1.5A
		-	461	540		I _F = 2A
		-	509	600		I _F = 3A
		-	450	-		I _F = 2A, T _A = +100°C
Reverse Current	I _R	-	10	40	μA	V _R = 30V
		-	0.6	-	mA	V _R = 30V, T _A = +85°C
Diode Capacitance	C _D	-	65	-	pF	f = 1MHz, V _R = 30V
Reverse Recovery Time	t _{RR}	-	6	-	ns	Switched from I _F = 500mA to V _R = 5.5V
Reverse Recovery Charge	Q _{RR}	-	685	-	nC	Measured @ I _R 50mA. di/dt = 500mA/ns. R _{SOURCE} = 6Ω; R _{LOAD} = 10Ω

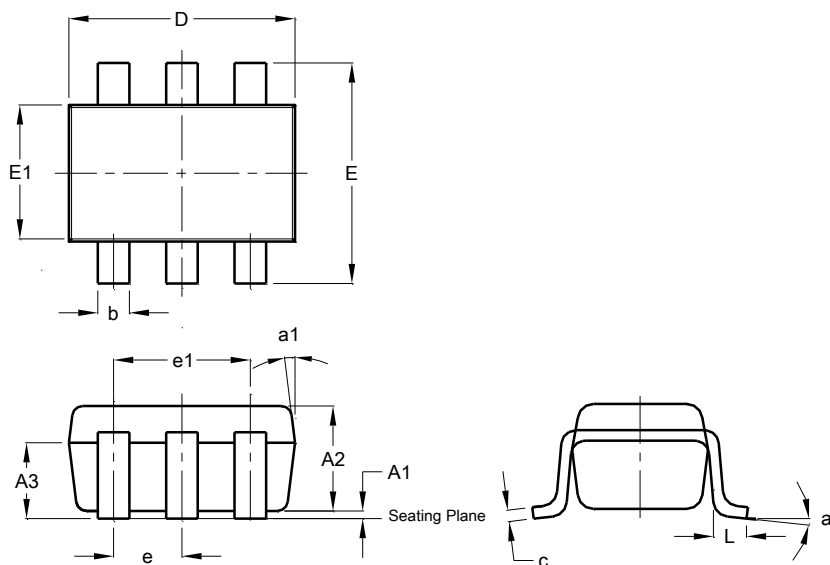
Note: 7. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle < 2%.



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26

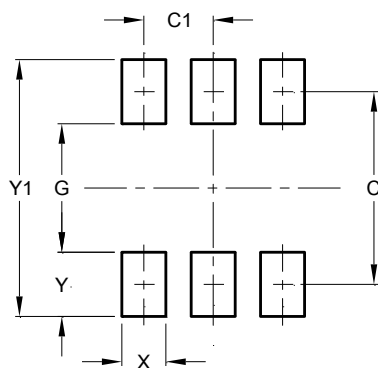


SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT26



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

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